



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application No.: 10/007,631

Atty. Docket No.: S01-079

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Art Unit: 2815

Applicants: Daniel S. Pickard et al.

Examiner: Joseph H. Nguyen

Title: ELECTRON BOMBARDMENT OF WIDE BANDGAP  
SEMICONDUCTORS FOR GENERATING HIGH BRIGHTNESS AND  
NARROW ENERGY SPREAD EMISSION ELECTRONS

CERTIFICATE OF MAILING

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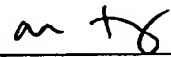
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Sir:

Applicant responds to the Office action mailed on 06/07/2005 as follows:

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